

Max-Planck-Institut für Physik (Werner-Heisenberg-Institut)



Holographic Noise

1308.1920, 1407.7526, 1507.02280, 1603.09625 with M. Araújo, A. Farahi, J.M. Lizana L.A. Pando-Zayas, I. Salazar Landea A. Scardicchio

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Disordered holographic Superconductors



[→ High-Tc Superconductors]

Disordered brane intersections (D3/D5)



Disordered chemical potential

Gauge/Gravity



Disorder is cool

Anderson Localization (1958):

[e⁻ in a random potential...]











Disorder is cool

• Anderson Localization (1958).



[Billy et al, Nature 453(2008)]

Disorder is cool

>SC to insulator disorder-induced phase transition



Disorder is cool

> Graphene (near charge neutrality)



- ► (Strongly coupled) Quantum Critical Point
- Graphene as strongly coupled relativistic Dirac fluid [Observed in Crossno et al, Science'16, 1509.04713]
 [Hydro model in Lucas et al, Science'16, 1510.01738]

Disorder + strong interactions = Challenge!

> Graphene



Holographic Disorder

> DISORDERED HOLOGRAPHIC SUPERCONDUCTORS

> DISORDERED TRANSPORT (STRANGE METALS): LUCAS, SACHDEV, SCHALM'14; DONOS, GAUNTLETT'14, O'KEEFFE, PEET'14; HARTNOLL, RAMIREZ, SANTOS'15

> DISORDERED FIXED POINTS: HARTNOLL, SANTOS'14; GARCIA, LOUREIRO'15

> DISORDERED HYDRO (-> GRAPHENE): LUCAS ET AL'15

> DISORDERED BRANES

Disordered Chemical Potential



- $k_0 \sim$ 1/(System Size). [IR Scale]
- $k_* \sim$ 1/Correlation length [UV Scale]

* [in units of T]

WE SET: $k_0 = 1/10$, and 10 modes

Dirty Holographic Superconductors

[1308.1920]

Holo SC



[Hartnoll et al'08]



$$S = \int d^4x \sqrt{-g} \left(-\frac{1}{4} F_{ab} F^{ab} - (D_{\mu} \Psi) (D^{\mu} \Psi)^{\dagger} - m^2 \Psi^{\dagger} \Psi \right)$$

in (3+1) Neutral Black Brane
[Probe Limit] 2 PDEs

> Results: The Inhomogeneous Condensate [1507.02280]





> Results: Disorder-induced Phase Transition



> SC to insulator disorder-induced phase transition



+

> Holography: Disorder-induced Phase Transition



- ENHANCEMENT OF <CONDENSATE>
- (HINTS OF) HIGGS MODE
- NON MEAN-FIELD PHASE TRANSITION

Noisy Branes

[1603.09625]

D3/D5 Intersection

0123456789D3XXXX-------D5XXX-XXX----

2d (strongly coupled) matter → Graphene?

3+1 N=4 SYM + (2+1) hypermultiplet

> Gravity Dual



> Setup: D3/D5 @ finite T and μ

* Nonzero Temperature N_c Black D3-branes



 $(\operatorname{Sch} - AdS_5) \times S^5$

* Charge Density (matter in the fdtal.):

 $A_{\mu} \sim J_{\mu}$ U(1) Worldvolume gauge field

 $A_t = \mu - \rho/r + O(r^{-2})$ Chemical Charge potential density

 \star D5 along (x,y) and wrapping $S^2 \subset S^5$

$$\chi \equiv \cos \theta = \chi(z, x)$$

$$A_t(z, x)$$

$$M = A_t(z, x$$

$$ds^{2} = \frac{L^{2}}{z^{2}} \left(-\frac{f(z)^{2}}{h(z)} dt^{2} + h(z) d\vec{x}^{2} + dz^{2} \right) + L^{2} d\Omega_{5}^{2}$$

and
$$d\Omega_{5}^{2} = d\theta^{2} + \sin^{2}\theta \, d\Omega_{2}^{2} + \cos^{2}\theta \, d\tilde{\Omega}_{2}^{2}$$

> Setup: D3/D5 @ finite T and μ

* Nonzero Temperature N_c Black D3-branes



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Chemical / potential



Only BH embeddings at ρ≠0 [Kobayashi et al'06]

★ Phase Diagram







[Meson melting: Hoyos et al'06]

Noisy Branes

[1603.09625] [See also: Ryu, Takayanagi, Ugajin'11; Ikeda, Lucas, Nakai'16]

100

> Adding noise ...

D3/D5



Numerics







>D3/D5. Results

m = 0.5 $\mu(x) = 15 + \text{noise}(x)$

$$k_0 = \frac{1}{10}$$
, 10 modes

UV

 \mathcal{Z}





Charge density enhancement

Quark condensate



 $\langle \rho \rangle \neq \langle \rho \rangle(w) ; \qquad (\rho \ll 1)$ $\langle \rho \rangle \propto w^2$; $(\rho \gg 1)$

Can be shown analytically (as perturbation of clean system)



$$\begin{split} \langle c \rangle &\neq \langle c \rangle(w) \, ; \qquad (\rho \gg 1) \\ \langle c \rangle \propto w^2 \, ; \qquad (\rho \ll 1) \end{split}$$

Noisy Conductivity

Noisy charged D5





Fluctuations \Rightarrow Constant E-field ($\mathfrak{e}_i = 1$) @ bdry

$$A_{i}(z, x, t) = a_{i}(z, x) e^{i\omega t}, \ F_{ti}(0, x) = (i\omega \mathfrak{e}_{i}) e^{i\omega t}; \quad (i = x, y)$$

$$\sigma_i(\omega, x) = \frac{j_i}{i\omega \, \mathfrak{e}_{\mathfrak{i}}} = \lim_{z \to 0} \frac{f_{iz}}{f_{ti}} \, ; \, (i = x, y) \lim_{\substack{\text{perponsed} \\ nesponsed}} f_{ij}(\omega, x) = \frac{j_i}{i\omega \, \mathfrak{e}_{\mathfrak{i}}} = \lim_{z \to 0} \frac{f_{iz}}{f_{ti}} \, ; \, (i = x, y) \lim_{\substack{\text{perponsed} \\ nesponsed}} f_{ij}(\omega, x) = \frac{j_i}{i\omega \, \mathfrak{e}_{\mathfrak{i}}} = \lim_{z \to 0} \frac{f_{iz}}{f_{ti}} \, ; \, (i = x, y) \lim_{\substack{\text{perponsed} \\ nesponsed}} f_{ij}(\omega, x) = \frac{j_i}{i\omega \, \mathfrak{e}_{\mathfrak{i}}} = \lim_{z \to 0} \frac{f_{iz}}{f_{ti}} \, ; \, (i = x, y) \lim_{\substack{\text{perponsed} \\ nesponsed}} f_{ij}(\omega, x) = \frac{j_i}{i\omega \, \mathfrak{e}_{\mathfrak{i}}} = \lim_{z \to 0} \frac{f_{iz}}{f_{ti}} \, ; \, (i = x, y) \lim_{\substack{\text{perponsed} \\ nesponsed}} f_{ij}(\omega, x) = \frac{j_i}{i\omega \, \mathfrak{e}_{\mathfrak{i}}} = \lim_{x \to 0} \frac{f_{iz}}{f_{ti}} \, ; \, (i = x, y) \lim_{\substack{\text{perponsed} \\ nesponsed}} f_{ij}(\omega, x) = \frac{j_i}{i\omega \, \mathfrak{e}_{\mathfrak{i}}} \, ; \, (i = x, y) \lim_{\substack{\text{perponsed} \\ nesponsed}} f_{ij}(\omega, x) = \frac{j_i}{i\omega \, \mathfrak{e}_{\mathfrak{i}}} \, ; \, (i = x, y) \lim_{\substack{nesponsed} \\ nesponsed}} f_{ij}(\omega, x) = \frac{j_i}{i\omega \, \mathfrak{e}_{\mathfrak{i}}} \, ; \, (i = x, y) \lim_{\substack{nesponsed} \\ nesponsed} f_{ij}(\omega, x) = \frac{j_i}{i\omega \, \mathfrak{e}_{\mathfrak{i}}} \, ; \, (i = x, y) \lim_{\substack{nesponsed} \\ nesponsed} f_{ij}(\omega, x) = \frac{j_i}{i\omega \, \mathfrak{e}_{\mathfrak{i}}} \, ; \, (i = x, y) \lim_{\substack{nesponsed} \\ nesponsed} f_{ij}(\omega, x) = \frac{j_i}{i\omega \, \mathfrak{e}_{\mathfrak{i}}} \, ; \, (i = x, y) \lim_{\substack{nesponsed} \\ nesponsed} f_{ij}(\omega, x) = \frac{j_i}{i\omega \, \mathfrak{e}_{\mathfrak{i}}} \, ; \, (i = x, y) \lim_{\substack{nesponsed} \\ nesponsed} f_{ij}(\omega, x) = \frac{j_i}{i\omega \, \mathfrak{e}_{\mathfrak{i}}} \, ; \, (i = x, y) \lim_{\substack{nesponsed} \\ nesponsed} f_{ij}(\omega, x) = \frac{j_i}{i\omega \, \mathfrak{e}_{\mathfrak{i}}} \, ; \, (i = x, y) \lim_{\substack{nesponsed} \\ nesponsed} f_{ij}(\omega, x) = \frac{j_i}{i\omega \, \mathfrak{e}_{\mathfrak{i}}} \, ; \, (i = x, y) \lim_{\substack{nesponsed} \\ nesponsed} f_{ij}(\omega, x) = \frac{j_i}{i\omega \, \mathfrak{e}_{\mathfrak{i}}} \, ; \, (i = x, y) \lim_{\substack{nesponsed} \\ nesponsed} f_{ij}(\omega, x) = \frac{j_i}{i\omega \, \mathfrak{e}_{\mathfrak{i}}} \, ; \, (i = x, y) \lim_{\substack{nesponsed} \\ nesponsed} f_{ij}(\omega, x) = \frac{j_i}{i\omega \, \mathfrak{e}_{\mathfrak{i}}} \, ; \, (i = x, y) \lim_{\substack{nesponsed} \\ nesponsed} f_{ij}(\omega, x) = \frac{j_i}{i\omega \, \mathfrak{e}_{\mathfrak{i}}} \, ; \, (i = x, y) \lim_{\substack{nesponsed} \\ nesponsed} f_{ij}(\omega, x) = \frac{j_i}{i\omega \, \mathfrak{e}_{\mathfrak{i}}} \, ; \, (i = x, y) \lim_{\substack{nesponsed} \\ nesponsed} f_{ij}(\omega, x) = \frac{j_i}{i\omega \, \mathfrak{e}_{\mathfrak{i}}$$

 $\sigma_x\equiv\sigma$ ($a_x,a_t,\delta\chi\equiv c$) coupled 3 linear PDEs $[a_z=0 \ gauge]$

Noisy Conductivity



DC Conductivity vs Charge Density

> In Graphene...

i) $\exists \sigma \text{ minimal } @ \text{CNP}$ ii) $\sigma \propto n$ up to n* iii) σ sublinear for high n

[Hwang et al, PRL'98]

• Experimental Conductivity [Tan et al, PRL'99]



> Clean D3/D5

 $\sigma = \sqrt{2 + \rho^2/2}$

$$\sigma \sim
ho^2, \ (
ho \sim 0)$$

 $\sigma \sim
ho, \ (
ho
ightarrow \infty)$ linear conductivity

What if we add disorder?



DC Conductivity vs Charge Density

[from here on: massless 'quarks']

Moderate Noise (µ(x)>0)



Non-linear conductivity?



Numerics (w = 3)

can be proven analytically (for moderate noise)

DC Conductivity at Strong Disorder

Increase noise... \rightarrow what if $\mu(x) < 0$?



Expected in graphene (e--hole puddles present)

Non-linear conductivity?

DC Conductivity at Strong Disorder

 $k_0 = \frac{1}{10}$, 10 modes

> 'Strong disorder' ($w \ge 5$) $\Rightarrow e^-$ - hole puddles appear



 ρ Charge density

DC Conductivity at Strong Disorder

> Semi-analytic approximation @ strong disorder

(approximating the setup by a succession (along x) of homogeneous systems \rightarrow gradients neglected)



DC Conductivity vs Charge Density

> Noisy branes @ strong disorder



• σ DECREASE @ HIGH ρ

OUTLINE

- > CHALLENGE: DISORDER + STRONG INTERACTIONS 🗸
- > DIRTY HOLO SCs: islands of SC -> Disorder-induced PT
- > NOISY BRANES: 2+1 matter + disorder
- > NOISY Conductivity (strong noise): Sub-linear at 'large ρ ' 🗸
- > Epic Challenges: backreaction (smearing?), 2d noise (thin films, graphene, disorder SC fixed points, QHE models?



and now... some SUPPLEMENTARY SLIPES

> Conductivity. `Weak Noise'

• Small ρ . Numerics



 $k_0 = \frac{1}{10}$, 10 modes





σ - Decrease

> Conductivity. 'Weak Noise' (~ ignoring gradients along x)

• Homogeneous limit:
$$\sigma_{DC} = \left\langle \frac{1}{\frac{1}{L} \int_0^{L_x} dx \frac{2}{\sqrt{4+\rho^2}}} \right\rangle_{noise}$$
noise

Noise strength expansion: ۲

$$\mu = \mu_0 \left(1 + \frac{w}{25} n(x) \right) \to \rho(n(x)) \quad \text{in} \quad \sigma_{\rm DC} = \left\langle \frac{1}{\frac{1}{L} \int_0^{L_x} dx \, \frac{2}{\sqrt{4 + \rho(x)^2}}} \right\rangle_{\rm noise}$$

 $\sigma_{\rm DC}(w)$ expand in powers of w $\rho\approx\sqrt{2}\mu\,;\qquad (\rho\ll 1)$ $\rho \approx 0.291 \mu^2 \, ; \qquad (\rho \gg 1)$

> Conductivity. `Weak Noise'

• Small
$$\rho$$
 $\sigma_{\rm DC} = 1 + \frac{d^2 \mu_0^2}{8} \left(1 + \frac{w^2}{25^2} \frac{1}{L} \left\langle \int_0^L dx \, n(x)^2 \right\rangle_{\rm noise} \right) + O(\mu_0^4, \, \tilde{w}^3)$

o - Enhancement

•
$$\sigma_{\rm DC} \approx 1 + \frac{\mu_0^2}{4} \left(1 + \frac{w^2}{25^2} \, \frac{\#(\text{modes})}{2} \right)$$

• Large
$$\boldsymbol{\rho}$$
 $\sigma_{\mathrm{DC}} = \frac{c\,\mu_0^2}{2} \left(1 - w^2 \frac{3}{25^2} \frac{1}{L} \left\langle \int_0^L dx \, n(x)^2 \right\rangle_{\mathrm{noise}} \right) + O(\mu_0^{-2}, \, w^3)$

•
$$\sigma_{\rm DC} \approx \frac{0.291 \mu_0^2}{2} \left(1 - w^2 \frac{3}{25^2} \frac{\#(\text{modes})}{2} \right)$$

>Noise II:

$$\mu(x) = \mu_0 + w \,\mu_0 \sum_{k=k_0}^{k_*} \sqrt{S(k)} \cos(k \, x + \delta_k)$$

• Flat Spectrum
$$S(k) = 1$$

 $\langle \mu(x) \, \mu(x') \rangle - \mu_0^2 \xrightarrow{k_* \to \infty} (w \, \mu_0)^2 \, \delta(x' - x)$ Gaussian noise



> Noise III (Solving...)



> Noise IU (UU & IR Scales)





> Noise U:

$$\mu(x) = \mu_0 + w \,\mu_0 \sum_{k=k_0}^{k_*} \sqrt{S(k)} \cos(k \, x + \delta_k)$$

• Flat Spectrum
$$\mu(x) = \mu_0 + \bar{V} \sum_{k=k_0}^{\kappa_*} \cos(k \, x + \delta_k)$$

Gaussian noise
$$(k_* \to \infty)$$

 $\langle \mu(x) \, \mu(x') \rangle - \mu_0^2 = \bar{V}^2 \, \delta(x - x')$ $\left[\bar{V} \right] = \frac{1}{2}$

1

> Harris Criterion:

 $\left[\bar{V}\right] > 0 \longrightarrow 1$ d Noisy $\mu(x)$ is relevant 2d Noisy $\mu(x) \longrightarrow \left[\bar{V}\right] = 0 \longrightarrow marginal$

> Noise UI:

$$\mu(x) = \mu_0 + w \,\mu_0 \sum_{k=k_0}^{k_*} \sqrt{S(k)} \cos(k \, x + \delta_k)$$

$$\bullet$$
 Power Spectrum $S(k)=\frac{1}{k^{2\alpha}}$



$$\langle \mu(x)\,\mu(x')\rangle - \mu_0^2 \sim \frac{k_0^{-2\alpha}}{x}\,\cos(k_0x) + \dots \longrightarrow \xi \sim$$

$$\xi \sim \frac{1}{k_0} \sim L$$

> Review: Holo (s-wave) Superconductor



> Review: Holo (s-wave) Superconductor



> Review: Holo (s-wave) Superconductor

> Setup:

Т

1.0 T_c

Maxwell-Einstein + scalar
$$\mathcal{S} = \int dx^4 \sqrt{-g} \left[\frac{R}{\mathcal{K}} + \frac{6}{\mathcal{K}L^2} - \frac{1}{4}F_{\mu\nu}F^{\mu\nu} - |(\partial_\mu - iqA_\mu)\Psi|^2 - m^2 |\Psi|^2 \right]$$

> Looking for superconducting solutions:



> Results: 'phase diagram'





P-WAVE SUPERCONDUCTOR [1407.7526]

> **Results:** Phase transition @ finite disorder

> Average of the condensate vs Temperature...





> σ_AC: Large disorder & Higgs mode(?)



> σ_AC: Large disorder & Higgs mode(?)

The Goldstone QNM has a massive partner ...

> Background: Charge Density

• Charge Density vs Noise Strength \Rightarrow Study $\rho(\mu)$ clean system

• Homogeneous (massless) case:

$$\begin{split} \rho &\approx \sqrt{2}\mu \,; \qquad (\rho \ll 1) \\ \rho &\approx 0.291 \mu^2 \,; \qquad (\rho \gg 1) \end{split}$$

• Assume

$$\mu = \mu_0 \left(1 + w \operatorname{noise}(x)\right)$$

$$(\operatorname{noise}(x))$$

$$\langle \rho \rangle \neq \langle \rho \rangle(w) ; \quad (\rho \ll 1)$$

$$\langle \rho \rangle \propto w^2 ; \quad (\rho \gg 1)$$
Charge Density Enhancement

> Conductivity. 'Weak Noise' (~ ignoring gradients along x)

• Homogeneous limit:
$$\sigma_{DC} = \left\langle \frac{1}{\frac{1}{L} \int_0^{L_x} dx \frac{2}{\sqrt{4+\rho^2}}} \right\rangle_{noise}$$
noise

Noise strength expansion: ۲

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 $\sigma_{\rm DC}(w)$ expand in powers of w $\rho\approx\sqrt{2}\mu\,;\qquad (\rho\ll 1)$ $\rho \approx 0.291 \mu^2 \, ; \qquad (\rho \gg 1)$

> Conductivity. 'Strong Noise' [pseudo-analytics]

- (Pseudo-analytic) DC Conductivity at all orders in w -

•
$$\sigma_{\rm DC} = \left\langle \frac{1}{\frac{1}{L} \int_0^{L_x} dx \frac{2}{\sqrt{4+\rho(x)^2}}} \right\rangle_{\rm noise}$$
 ~ Averaging over
homogeneous(x)
systems
• $\mu(x) = \frac{\rho(x)}{\sqrt{2}} {}_1F_2\left(\frac{1}{4}, \frac{1}{2}, \frac{5}{4}; -\frac{\rho(x)^2}{4}\right)$
• Invert (numerically) for $\rho(\mu(x)) \longrightarrow$ Integrate $\longrightarrow \sigma_{\rm DC}(\mu_0, w)$

• Large charge (small w) limit Linear behavior! $\sigma_{\rm DC} \approx \frac{1 - 3 \left(w^2/25^2 \right) \Delta + \left(9\Delta^2/25^4 - 5\Delta_4/25^4 \right) w^4}{1 + \left(w^2/25^2 \right) \Delta} \frac{\langle \rho \rangle}{2}$

$$\Delta = \left\langle \frac{1}{L} \int dx \, n(x)^2 \right\rangle_{\text{noise}}$$

$$\Delta_4 = \left\langle \frac{1}{L} \int dx \, n(x)^4 \right\rangle_{\text{noise}}$$

we'll see that $\sigma_{
m DC} \propto \langle
ho
angle$ true at all orders in w